TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC86F,TC74VHC86FN,TC74VHC86FT

#### Quad Exclusive OR Gate

The TC74VHC86 is an advanced high speed CMOS QUAD EXCLUSIVE OR GATE fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

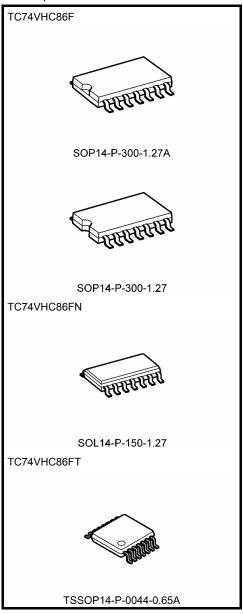
The internal circuit is includes on output buffer, which provide high noise immunity and stable output.

An Input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and on two supply system such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

- High speed:  $t_{pd} = 4.8 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 2 \mu A \text{ (max)}$  at  $T_a = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC (opr)} = 2 V \text{ to } 5.5 V$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS86

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

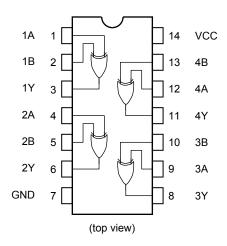
 SOP14-P-300-1.27A
 : 0.18 g (typ.)

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 : 0.18 g (typ.)

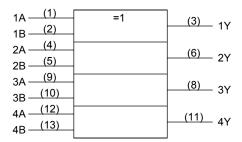
 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

## **Pin Assignment**



# **IEC Logic Symbol**



## **Truth Table**

| Α | В | Υ |
|---|---|---|
| L | L | L |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

## **Absolute Maximum Ratings (Note)**

| Characteristics       | Symbol           | Rating                        | Unit |
|-----------------------|------------------|-------------------------------|------|
| Supply voltage range  | V <sub>CC</sub>  | −0.5 to 7.0                   | V    |
| DC input voltage      | V <sub>IN</sub>  | −0.5 to 7.0                   | V    |
| DC output voltage     | V <sub>OUT</sub> | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current   | I <sub>IK</sub>  | -20                           | mA   |
| Output diode current  | lok              | ±20                           | mA   |
| DC output current     | lout             | ±25                           | mA   |
| DC VCC/ground current | I <sub>CC</sub>  | ±50                           | mA   |
| Power dissipation     | PD               | 180                           | mW   |
| Storage temperature   | T <sub>stg</sub> | –65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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# **Recommended Operating Conditions (Note)**

| Characteristics          | Symbol           | Rating                                       | Unit   |  |
|--------------------------|------------------|--|--------|--|
| Supply voltage           | $V_{CC}$         | 2.0 to 5.5                                   | V      |  |
| Input voltage            | V <sub>IN</sub>  | 0 to 5.5                                     | V      |  |
| Output voltage           | V <sub>OUT</sub> | 0 to V <sub>CC</sub>                         | V      |  |
| Operating temperature    | T <sub>opr</sub> | -40 to 85                                    | °C     |  |
| Input rise and fall time | dt/dv            | 0 to 100 (V <sub>CC</sub> = $3.3 \pm 0.3$ V) | ns/V   |  |
| input rise and rail time | uluv             | 0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)    | 115/ V |  |

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

|                           |                 |  |  | Ta = 25°C                       |                                   |                        | Ta = -40 to 85°C                  |                                   |                                   |      |
|---------------------------|-----------------|--|--|---------------------------------|-----------------------------------|------------------------|-----------------------------------|-----------------------------------|-----------------------------------|------|
| Characteristics           | Symbol          | bol Test Condition                       |  | V <sub>CC</sub> (V)             | Min                               | Тур.                   | Max                               | Min                               | Max                               | Unit |
| High-level input voltage  | V <sub>IH</sub> | _  |  | 2.0<br>3.0<br>to<br>5.5         | 1.50<br>V <sub>CC</sub> ×<br>0.7  |                        | _                                 | 1.50<br>V <sub>CC</sub> ×<br>0.7  |                                   | V    |
| Low-level input voltage   | $V_{IL}$        | _  |  | 2.0<br>3.0<br>to<br>5.5         |                                   |                        | 0.50<br>V <sub>CC</sub> ×<br>0.3  | _                                 | 0.50<br>V <sub>CC</sub> ×<br>0.3  | V    |
| High-level output voltage | V <sub>ОН</sub> | $V_{IN} = V_{IH}$ or $V_{IL}$            | $I_{OH} = -50 \mu A$ $I_{OH} = -4 mA$ $I_{OH} = -8 mA$ | 2.0<br>3.0<br>4.5<br>3.0<br>4.5 | 1.9<br>2.9<br>4.4<br>2.58<br>3.94 | 2.0<br>3.0<br>4.5      |                                   | 1.9<br>2.9<br>4.4<br>2.48<br>3.80 |                                   | V    |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH}$ or $V_{IL}$            | $I_{OL} = 50 \mu A$ $I_{OL} = 4 mA$ $I_{OL} = 8 mA$    | 2.0<br>3.0<br>4.5<br>3.0<br>4.5 |                                   | 0.0<br>0.0<br>0.0<br>— | 0.1<br>0.1<br>0.1<br>0.36<br>0.36 | _<br>_<br>_<br>_                  | 0.1<br>0.1<br>0.1<br>0.44<br>0.44 | V    |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           |  | 0 to<br>5.5                     |                                   |                        | ±0.1                              | _                                 | ±1.0                              | μА   |
| Quiescent supply current  | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |  | 5.5                             | _                                 | _                      | 2.0                               | _                                 | 20.0                              | μА   |

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## AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics Symbol           | Test Condition   |                     |                     | Ta = 25°C |      |     | Ta = -40 to 85°C |     | Unit  |      |
|----------------------------------|------------------|---------------------|---------------------|-----------|------|-----|------------------|-----|-------|------|
|                                  |                  | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min       | Тур. | Max | Min              | Max | Offic |      |
| Propagation delay tpLH time tpHL |                  |                     | 3.3 ± 0.3           | 15        | _    | 7.0 | 11.0             | 1.0 | 13.0  | - ns |
|                                  | t <sub>pLH</sub> |                     |                     | 50        |      | 9.5 | 14.5             | 1.0 | 16.5  |      |
|                                  | t <sub>pHL</sub> |                     | 5.0 ± 0.5           | 15        | _    | 4.8 | 6.8              | 1.0 | 8.0   |      |
|                                  |                  |                     |                     | 50        | _    | 6.3 | 8.8              | 1.0 | 10.0  |      |
| Input capacitance                | C <sub>IN</sub>  |                     | _                   |           | _    | 4   | 10               | _   | 10    | pF   |
| Power dissipation capacitance    | C <sub>PD</sub>  |                     |                     | (Note)    |      | 18  | _                | _   |       | pF   |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

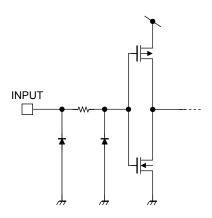
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$ 

## Noise Characteristics (input: $t_r = t_f = 3$ ns)

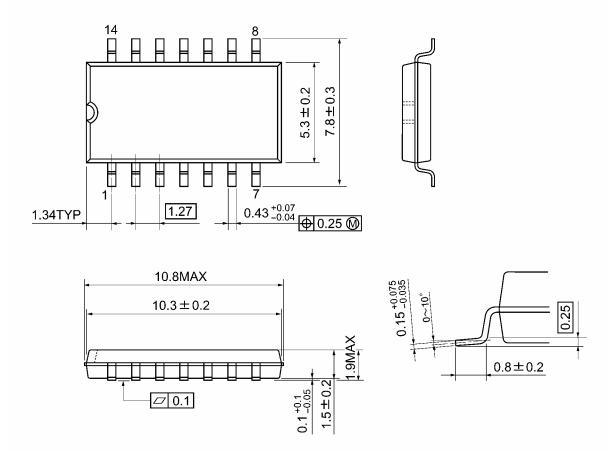
| Characteristics                              | Symbol           | Test Condition         |                     | Ta = 25°C |       |      |
|--|------------------|------------------------|---------------------|-----------|-------|------|
|  |                  | Test Condition         | V <sub>CC</sub> (V) | Тур.      | Limit | Unit |
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 0.3       | 0.8   | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -0.3      | -0.8  | V    |
| Minimum high level dynamic input voltage     | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _         | 3.5   | ٧    |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _         | 1.5   | V    |

## **Input Equivalent Circuit**



# **Package Dimensions**

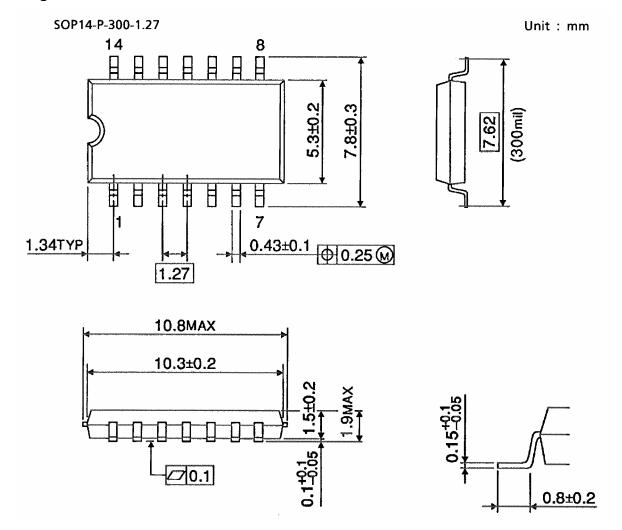
SOP14-P-300-1.27A Unit: mm



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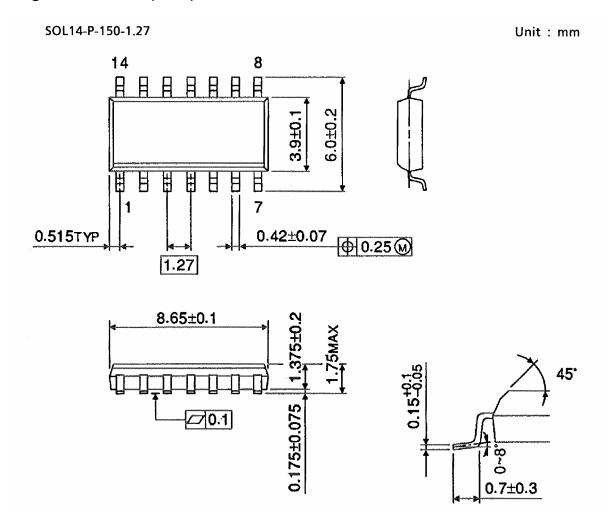
Weight: 0.18 g (typ.)

## **Package Dimensions**



Weight: 0.18 g (typ.)

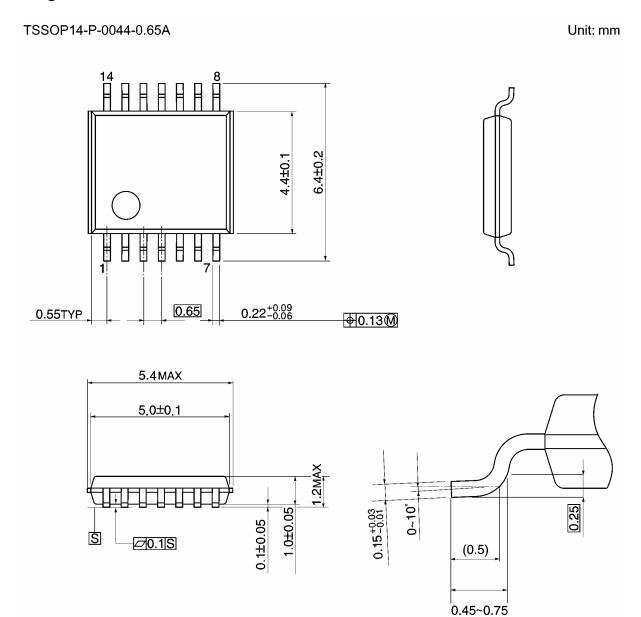
# **Package Dimensions (Note)**



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

# **Package Dimensions**



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Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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